The Future of Analog IC Technology

NB670

24V, High Current

Synchronous Buck Converter With LDO

DESCRIPTION

The NB670 is a fully integrated high frequency synchronous rectified step-down switch mode converter with 3.3V fixed output voltage. It offers very compact solution to achieve 6A continuous output current and 9A peak output current over a wide input supply range with excellent load and line regulation. The NB670 operates at high efficiency over a wide output current load range. Constant-On-Time (COT) control mode provides fast transient response and eases loop stabilization.

Under voltage lockout is internally set as 4.65 V. An open drain power good signal indicates the output is within its nominal voltage range.

NB670 also provides a 3.3V LDO, which can be used to power the external peripheries, such as the keyboard controller in the laptop computer. A 300kHz CLK is also available; its output can be used to drive an external charge pump, generating gate drive voltage for the load switches without reducing the main converter's efficiency.

Full protection features include OCP, OVP, UVP and thermal shut down.

The converter requires minimum number of external components and is available in QFN16 (3mmx3mm) package.

FEATURES

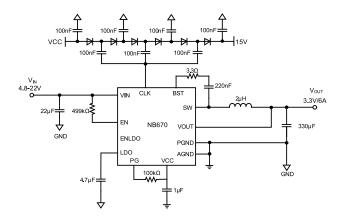
- Wide 5V to 24V Operating Input Range
- 3.3V Fixed Output Voltage
- Built-in 3.3V, 100mA LDO with Switches
- 6A Continuous Output Current
- 9A Peak Output Current
- 300kHZ CLK for External Charge Pump
- Low R_{DS}(ON) Internal Power MOSFETs
- Proprietary Switching Loss Reduction Technique
- Internal Soft Start
- Output Discharge
- 500kHZ Switching Frequency
- OCP, OVP, UVP Protection and Thermal Shutdown
- Latch off Reset via EN or Power Cycle

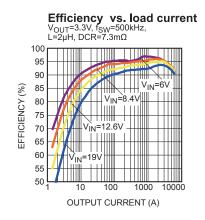
APPLICATIONS

- Laptop Computer
- Tablet PC
- Networking Systems
- Personal Video Recorders
- Flat Panel Television and Monitors
- Distributed Power Systems

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TYPICAL APPLICATION





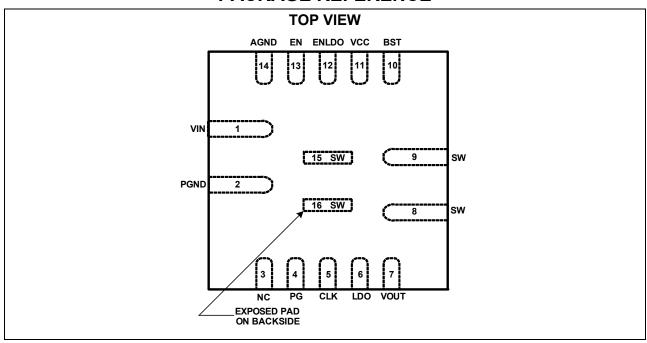


ORDERING INFORMATION

| Part Number* | Package | Top Marking |
|--------------|------------------|-------------|
| NB670GQ | QFN-16 (3mmx3mm) | ADZ |

* For Tape & Reel, add suffix -Z (e.g. NB670GQ-Z)

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)

| Supply Voltage V _{IN} | 24V |
|---|----------------|
| V _{SW} | -0.3V to 24.3V |
| V _{SW} (30ns) | |
| V _{SW} (5ns) | |
| V _{BST} | |
| V _{EN} | |
| V _{ENLDO} | 12V |
| Enable Current I _{EN} ⁽²⁾ | 2.5mA |
| All Other Pins | -0.3V to +5.5V |
| Continuous Power Dissipation (T | |
| QFN-16 | 1.8W |
| Junction Temperature | 150°C |
| Lead Temperature | |
| Storage Temperature6 | 65°C to +150°C |

Recommended Operating Conditions (4)

| Supply Voltage V _{IN} | 5V to 22V |
|---|----------------|
| Output Voltage V _{OUT} | 3.3V |
| Enable Current I _{EN} | 1mA |
| Operating Junction Temp. (T _J)4 | 40°C to +125°C |

| Thermal Resistance | e ⁽⁵⁾ | $oldsymbol{	heta}_{JA}$ | $\boldsymbol{\theta}_{JC}$ | |
|--------------------|------------------|-------------------------|----------------------------|------|
| QFN-16 (3mmx3mm) | | | 15 | °C/W |

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) Refer to Page 19 of Configuring the EN Control.
- 3) The maximum allowable power dissipation is a function of the maximum junction temperature T_J(MAX), the junction-to-ambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D(MAX)=(T_J(MAX)-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 5) Measured on JESD51-7, 4-layer PCB.



ELECTRICAL CHARACTERISTICS

 V_{IN} = 12V, T_J = 25°C, unless otherwise noted.

| Parameters | Symbol | Condition | Min | Тур | Max | Units |
|---|------------------------|---|-------|--------|-------|---------------------------|
| Supply Current | | | | | | |
| Supply Current (Shutdown) | I _{IN Shtdn} | V _{EN} = 0V | | 1 | 2 | μA |
| Supply Current (Quiescent) | I _{IN} | V_{EN} = 2V, V_{ENLDO} = 2V , V_{OUT} = 3.5V | 140 | 220 | 300 | μA |
| Supply Current (No load) | I _{IN} | V_{EN} = 2V, V_{ENLDO} = 2V, V_{OUT} = 3.35V, Io=0A | | 240 | | μA |
| Supply Current (Standby) | I _{IN_Stby} | $V_{EN} = 0V$, $V_{ENLDO} = 2V$, $I_{LDO} = 0A$ | 40 | 80 | 120 | μA |
| MOSFET | | | | | | |
| High-side Switch On Resistance | HS _{RDS-ON} | | | 30 | | mΩ |
| Low-side Switch On Resistance | LS _{RDS-ON} | | | 15 | | mΩ |
| Switch Leakage | SW _{LKG} | $V_{EN} = 0V$, $V_{SW} = 0V$ | | 0 | 1 | μA |
| Current Limit | | | | | | |
| Low-side Valley Current Limit | I _{LIMIT} | | 8 | 8.5 | 9.5 | Α |
| Switching frequency and minim | um off timer | | | | | |
| Switching Frequency | F _{SW} | | 400 | 500 | 600 | kHz |
| Minimum Off Time ⁽⁶⁾ | T _{OFF} | | | 350 | | ns |
| Over-voltage and Under-voltage | Protection | | | | | |
| OVP Threshold | V _{OVP} | | 125 | 130 | 135 | % V _{OUT Ref} |
| OVP Delay ⁽⁶⁾ | T _{OVPDEL} | | | 2.5 | | μs |
| UVP Threshold | V _{UVP} | | 55 | 60 | 65 | % V _{OUT Ref} |
| UVP Delay ⁽⁶⁾ | T _{UVPDEL} | | | 8 | | μs |
| Vout_Ref And Soft Start | | | | | | |
| Vout Ref Voltage | Vout_Ref | | 3.285 | 3.35 | 3.415 | V |
| Soft Start Time | T _{SS} | | 1.5 | 1.8 | 1.95 | ms |
| Enable And UVLO | | | | | | |
| Enable Input Low Voltage | VIL _{EN} | | 1.15 | 1.25 | 1.35 | V |
| Enable Hysteresis | V _{EN-HYS} | | | 100 | | mV |
| Enable Input Current | I _{EN} | $V_{EN} = 2V$ $V_{EN} = 0V$ | | 5 0 | | μA |
| Enable LDO Input Low Voltage | V _{ENLDO} | | 1.15 | 1.25 | 1.35 | V |
| Enable LDO Hysteresis | V _{ENLDO-HYS} | | | 100 | | mV |
| VCC Under Voltage Lockout Threshold Rising | VCC_{Vth} | | | 4.65 | 4.85 | V |
| VCC Under Voltage Lockout Threshold Hysteresis | VCC _{HYS} | | | 500 | | mV |



ELECTRICAL CHARACTERISTICS (continued)

 V_{IN} = 12V, T_J = 25°C, unless otherwise noted.

| Parameters | Symbol | Condition | Min | Тур | Max | Units |
|---------------------------------------|----------------------|--------------------------|------|------|------|----------------|
| CLK Output | | | | | | |
| CLK Output High Level Voltage | V_{CLKH} | I _{VcIk} = -5mA | 3.1 | 3.25 | 3.4 | V |
| CLK Output Low Level Voltage | V_{CLKL} | I _{VcIk} = 5mA | 0 | 0.05 | 0.1 | V |
| CLK Frequency | F _{CLK} | T _J = 25°C | | 300 | | kHz |
| LDO Regulator | | | | | | |
| LDO Regulator | V_{LDO} | | 3.25 | 3.35 | 3.45 | V |
| LDO Load Regulation | | I _{LDO} =50mA | | 5 | | % |
| LDO Load Capability | | Before switch-over | 70 | 90 | 120 | mA |
| LDO Load Capability | | After switch-over | 100 | | | mA |
| Switch Rdson | R_{Switch} | I _{LDO} =50mA | | 1.7 | 2.2 | Ω |
| VCC Regulator | | | | | | |
| VCC Regulator | V_{CC} | | 4.95 | 5.15 | 5.35 | V |
| VCC Load Regulation | | Icc=5mA | | 5 | | % |
| Power Good | | | | • | • | - |
| PG Rising (Good) | PG _{Vth-Hi} | | | 95 | | |
| PG Falling (Fault) | PG _{Vth-Lo} | | | 85 | | % |
| PG Rising (Fault) | PG _{Vth-Hi} | | | 115 | | V_{OUT_Ref} |
| PG Falling (Good) | PG _{Vth-Lo} | | | 105 | | |
| Power Good Lower to High Delay | PG_{Td} | | | 0.5 | | ms |
| Power Good Sink Current Capability | V_{PG} | Sink 4mA | | | 0.4 | V |
| Power Good Leakage Current | I _{PG LEAK} | V _{PG} = 3.3V | | | 100 | nA |
| Thermal Protection | | | | | | |
| Thermal Shutdown ⁽⁶⁾ | T_{SD} | | | 150 | | °C |
| Thermal Shutdown Hysteresis | | | | 25 | | °C |

Note:

⁶⁾ Guaranteed by design.



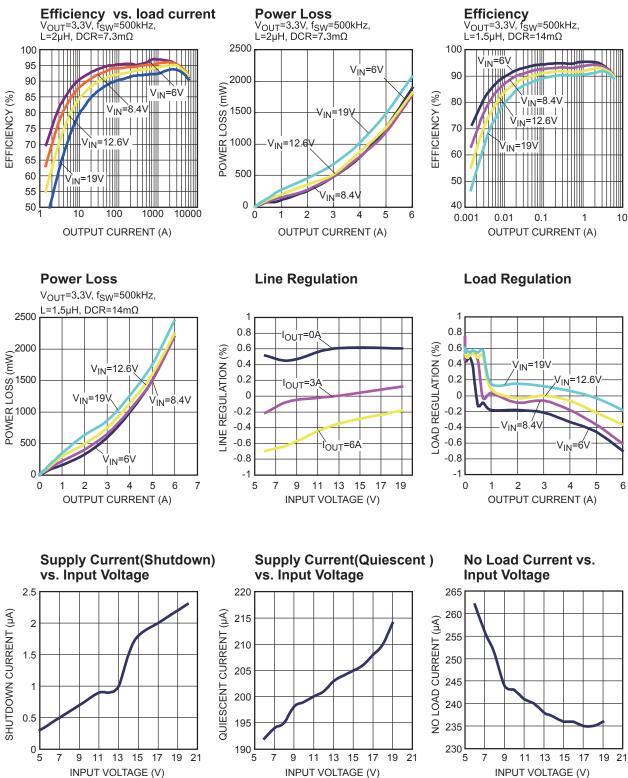
PIN FUNCTIONS

| NB670 operates from a +5V to +24V input rail. An input capacitor is needed decouple the input rail. Use wide PCB traces and multiple vias to make connection. PGND Power Ground. Use wide PCB traces and multiple vias to make the connection. NC Not connected. Power good output. The output of this pin is an open drain signal and is high in output voltage is higher than 95% of the nominal voltage. There is a delay from ≥ 95% to PGOOD goes high. CLK 300KHZ CLK output to drive the external charge pump Internal 3.3V LDO output. Decouple with a minimum 4.7µF ceramic capacitor close to the pin as possible. X7R or X5R grade dielectric ceramic capacitors recommended for their stable temperature characteristics. Once the output voltage of the Buck regulator is ready, it will switch over the output to save the power loss. Output voltage sense. For the NB670, the output of the Buck regulator is fixe 3.3V. VOUT pin is used to sense the output voltage of the Buck regulator, con this pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the duty cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the Iow-side switch and the internal diode fixes the negron to the switch and the internal diode fixes the negron to the switch and the internal diode fixes the negron to the switch switch and the internal diode fixes the negron to the switch switch and the internal diode fixes the negron to the switch and the internal diode fixes the negron to the switch and the internal diode fixes the negron to the switch switch driver. | PIN# | Name | Description |
|--|-------------|-------|--|
| 3 NC Not connected. Power good output. The output of this pin is an open drain signal and is high in output voltage is higher than 95% of the nominal voltage. There is a delay from 2 ≥ 95% to PGOOD goes high. 5 CLK 300kHZ CLK output to drive the external charge pump Internal 3.3V LDO output. Decouple with a minimum 4.7μF ceramic capacitors recommended for their stable temperature characteristics. Once the output voltage of the Buck regulator is ready, it will switch over the output to save the power loss. Output voltage sense. For the NB670, the output of the Buck regulator, con this pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the F duty cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the low-side switch and the internal diode fixes the negative during supply across the high-side switch driver. | 1 | VIN | Supply Voltage. The VIN pin supplies power for internal MOSFET and regulator. The NB670 operates from a +5V to +24V input rail. An input capacitor is needed to decouple the input rail. Use wide PCB traces and multiple vias to make the connection. |
| Power good output. The output of this pin is an open drain signal and is high in output voltage is higher than 95% of the nominal voltage. There is a delay from ≥ 95% to PGOOD goes high. 5 CLK 300kHZ CLK output to drive the external charge pump Internal 3.3V LDO output. Decouple with a minimum 4.7μF ceramic capacitor close to the pin as possible. X7R or X5R grade dielectric ceramic capacitors recommended for their stable temperature characteristics. Once the output voltage of the Buck regulator is ready, it will switch over the output to save the power loss. Output voltage sense. For the NB670, the output of the Buck regulator, con this pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the F duty cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the low-side switch and the internal diode fixes the negative up to the SW pattern. Bootstrap. A capacitor connected between SW and BST pins is required to for floating supply across the high-side switch driver. | 2 | PGND | Power Ground. Use wide PCB traces and multiple vias to make the connection. |
| 4 PG output voltage is higher than 95% of the nominal voltage. There is a delay from ≥ 95% to PGOOD goes high. 5 CLK 300kHZ CLK output to drive the external charge pump Internal 3.3V LDO output. Decouple with a minimum 4.7μF ceramic capacitors recommended for their stable temperature characteristics. Once the output voltage of the Buck regulator is ready, it will switch over the output to save the power loss. Output voltage sense. For the NB670, the output of the Buck regulator is fixe 3.3V VOUT pin is used to sense the output voltage of the Buck regulator, con this pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the fully cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the low-side switch and the internal diode fixes the negron-resistance of the SW pattern. Bootstrap. A capacitor connected between SW and BST pins is required to for floating supply across the high-side switch driver. | 3 | NC | Not connected. |
| Internal 3.3V LDO output. Decouple with a minimum 4.7μF ceramic capacitor close to the pin as possible. X7R or X5R grade dielectric ceramic capacitors recommended for their stable temperature characteristics. Once the output voltage of the Buck regulator is ready, it will switch over the output to save the power loss. Output voltage sense. For the NB670, the output of the Buck regulator is fixed 3.3V. VOUT pin is used to sense the output voltage of the Buck regulator, conthis pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the Foundation duty cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the low-side switch and the internal diode fixes the negative voltage. Use wide and short PCB traces to make the connection. Try to minimize area of the SW pattern. Bootstrap. A capacitor connected between SW and BST pins is required to for floating supply across the high-side switch driver. | 4 | PG | Power good output. The output of this pin is an open drain signal and is high if the output voltage is higher than 95% of the nominal voltage. There is a delay from Vout ≥ 95% to PGOOD goes high. |
| close to the pin as possible. X7R or X5R grade dielectric ceramic capacitors recommended for their stable temperature characteristics. Once the output voltage of the Buck regulator is ready, it will switch over the output to save the power loss. Output voltage sense. For the NB670, the output of the Buck regulator is fixed 3.3V. VOUT pin is used to sense the output voltage of the Buck regulator, conthis pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the Foundation on-resistance of the low-side switch and the internal diode fixes the negrobles. Switch SW pattern. BST Bootstrap. A capacitor connected between SW and BST pins is required to for floating supply across the high-side switch driver. | 5 | CLK | 300kHZ CLK output to drive the external charge pump |
| TOUT 3.3V. VOUT pin is used to sense the output voltage of the Buck regulator, conthis pin to the output capacitor of the regulator directly. This pin also acts as input of the 3.3V LDO switch over power input. Keep the VOUT sensing trace far away from the SW node. Vias should also avoided on the VOUT sensing trace. Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin driven up to the VIN voltage by the high-side switch during the on-time of the Fourier duty cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the low-side switch and the internal diode fixes the negative voltage. Use wide and short PCB traces to make the connection. Try to minimize area of the SW pattern. Bootstrap. A capacitor connected between SW and BST pins is required to for floating supply across the high-side switch driver. | 6 | LDO | Once the output voltage of the Buck regulator is ready, it will switch over the LDO |
| driven up to the VIN voltage by the high-side switch during the on-time of the F duty cycle. The inductor current drives the SW pin negative during the off-time. on-resistance of the low-side switch and the internal diode fixes the negative voltage. Use wide and short PCB traces to make the connection. Try to minimize area of the SW pattern. Bootstrap. A capacitor connected between SW and BST pins is required to for floating supply across the high-side switch driver. | 7 | VOUT | Keep the VOUT sensing trace far away from the SW node. Vias should also be |
| floating supply across the high-side switch driver. | Exposed Pad | SW | Switch Output. Connect this pin to the inductor and bootstrap capacitor. This pin is driven up to the VIN voltage by the high-side switch during the on-time of the PWM duty cycle. The inductor current drives the SW pin negative during the off-time. The on-resistance of the low-side switch and the internal diode fixes the negative voltage. Use wide and short PCB traces to make the connection. Try to minimize the area of the SW pattern. |
| Internal 5/ I DO output. The driver and control circuits are recovered from | 10 | BST | Bootstrap. A capacitor connected between SW and BST pins is required to form a floating supply across the high-side switch driver. |
| voltage. Decouple with a minimum 1µF ceramic capacitor as close to the pi | 11 | VCC | Internal 5V LDO output. The driver and control circuits are powered from this voltage. Decouple with a minimum 1µF ceramic capacitor as close to the pin as possible. X7R or X5R grade dielectric ceramic capacitors are recommended for their stable temperature characteristics. |
| 12 ENLDO 100mA LDO and VCC enable pin. ENLDO is internally pulled up to high. Leave pin open to enable the LDO. Drive it low to turn off all the regulators . | 12 | ENLDO | 100mA LDO and VCC enable pin. ENLDO is internally pulled up to high. Leave this pin open to enable the LDO. Drive it low to turn off all the regulators . |
| Buck regulator and CLK on or off. When the power supply of the control circu | 13 | EN | Buck regulator and charge pump clock enable pin. EN is a digital input that turns the Buck regulator and CLK on or off. When the power supply of the control circuit is ready, drive EN high to turn on the Buck regulator and charge pump clock, drive it low to turn them off. |
| 14 AGND Analog ground. The internal reference is referred to AGND. | 14 | AGND | Analog ground. The internal reference is referred to AGND. |



TYPICAL PERFORMANCE CHARACTERISTICS

Performance waveforms are tested on the evaluation board of the Design Example section. V_{IN} =12V, V_{OUT} =3.3V, L=2 μ H, T_{J} =+25°C, unless otherwise noted.

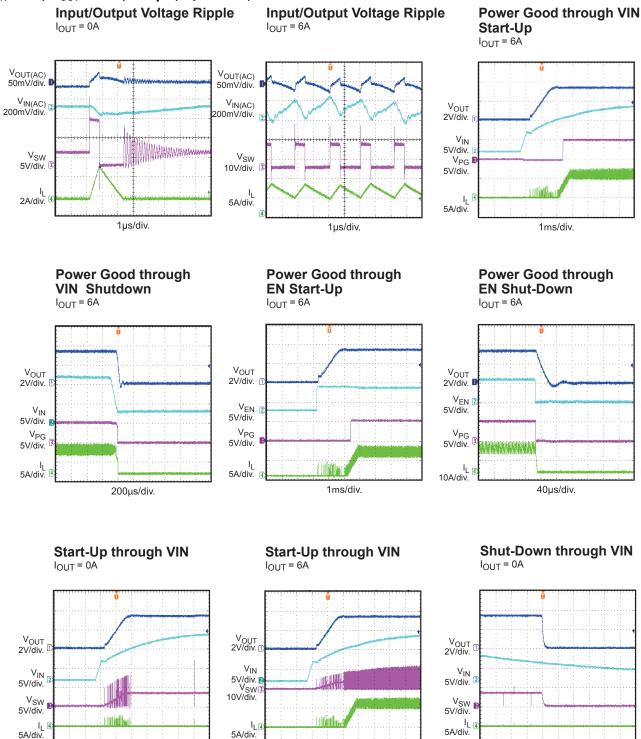


6



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Performance waveforms are tested on the evaluation board of the Design Example section. $V_{IN}=12V,\ V_{OUT}=3.3V,\ L=2\mu H,\ T_J=+25^{\circ}C,\ unless otherwise noted.$



1ms/div.

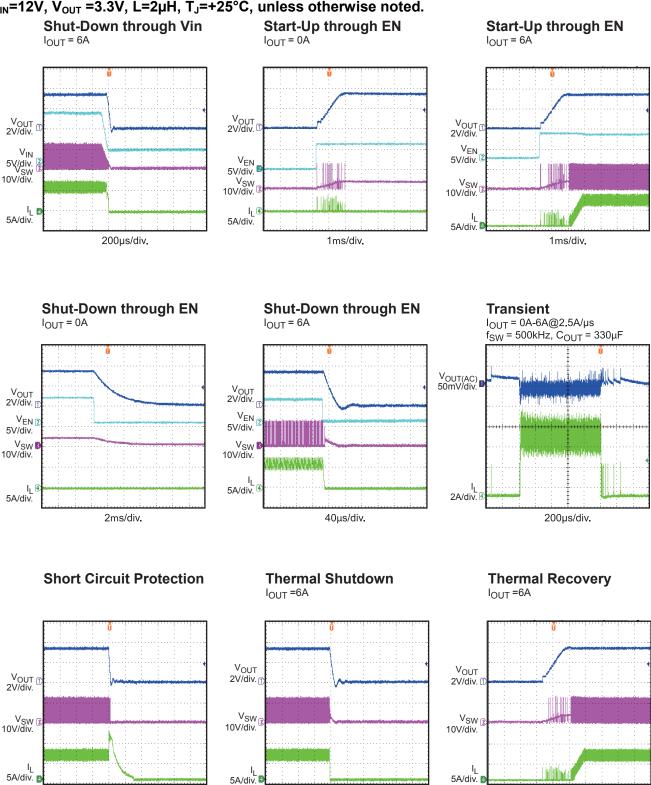
1ms/div.

40ms/div.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Performance waveforms are tested on the evaluation board of the Design Example section. $V_{IN}=12V,\ V_{OUT}=3.3V,\ L=2\mu H,\ T_J=+25^{\circ}C,\ unless otherwise noted.$



100µs/div.

100µs/div.

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1ms/div.



BLOCK DIAGRAM

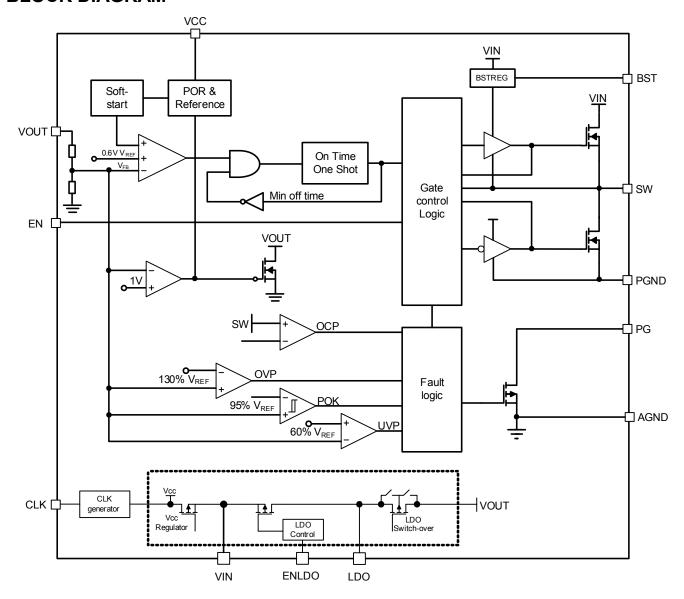


Figure 1—Functional Block Diagram



OPERATION

PWM Operation

The NB670 is fully integrated synchronous rectified step-down switch mode converter. Constant-on-time (COT) control is employed to provide fast transient response and easy loop stabilization. At the beginning of each cycle, the high-side MOSFET (HS-FET) is turned ON when the feedback voltage (V_{FB}) is below the reference voltage (V_{REF}), which indicates insufficient output voltage. The ON period is determined by the output voltage and input voltage to make the switching frequency fairy constant over input voltage range.

After the ON period elapses, the HS-FET is turned off, or becomes OFF state. It is turned ON again when V_{FB} drops below V_{REF} . By repeating operation this way, the converter regulates the output voltage. The integrated low-side MOSFET (LS-FET) is turned on when the HS-FET is in its OFF state to minimize the conduction loss. There will be a dead short between input and GND if both HS-FET and LS-FET are turned on at the same time. It's called shoot-through. In order to avoid shoot-through, a dead-time (DT) is internally generated between HS-FET off and LS-FET on, or LS-FET off and HS-FET on.

An internal compensation is applied for COT control to make a more stable operation even when ceramic capacitors are used as output capacitors, this internal compensation will then improve the jitter performance without affect the line or load regulation.

Heavy-Load Operation

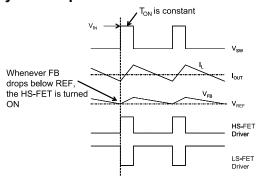


Figure 2—Heavy Load Operation

When the output current is high and the inductor current is always above zero amps, it is called continuous-conduction-mode (CCM). The CCM mode operation is shown in Figure 2 shown. When V_{FB} is below V_{REF} , HS-FET is turned on for a fixed interval. When the HS-FET is turned off, the LS-FET is turned on until next period.

In CCM mode operation, the switching frequency is fairly constant and it is called PWM mode.

Light-Load Operation

With the load decrease, the inductor current decrease too. Once the inductor current touch zero, the operation is transition from continuous-conduction-mode (CCM) to discontinuous-conduction-mode (DCM).

The light load operation is shown in Figure 3. When V_{FB} is below V_{REF}, HS-FET is turned on for a fixed interval which is determined by one- shot on-timer as equation 1 shown. When the HS-FET is turned off, the LS-FET is turned on until the inductor current reaches zero. In DCM operation, the V_{FB} does not reach V_{REF} when the inductor current is approaching zero. The LS-FET driver turns into tri-state (high Z) whenever the inductor current reaches zero. A current modulator takes over the control of LS-FET and limits the inductor current to less than -1mA. Hence, the output capacitors discharge slowly to GND through LS-FET. As a result, the efficiency at light load condition is greatly improved. At light load condition, the HS-FET is not turned ON as frequently as at heavy load condition. This is called skip mode.

At light load or no load condition, the output drops very slowly and the NB670 reduces the switching frequency naturally and then high efficiency is achieved at light load.

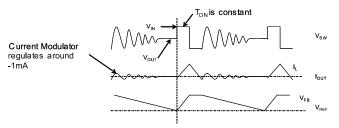


Figure 3—Light Load Operation

As the output current increases from the light load condition, the time period within which the current modulator regulates becomes shorter. The HS-FET is turned ON more frequently. Hence, the switching frequency increases correspondingly. The output current reaches the critical level when the current modulator time is zero. The critical level of the output current is determined as follows:

$$I_{OUT} = \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{2 \times L \times F_{SW} \times V_{IN}}$$
 (1)

It turns into PWM mode once the output current exceeds the critical level. After that, the switching frequency stays fairly constant over the output current range.

Jitter and FB Ramp Slope

Jitter occurs in both PWM and skip modes when noise in the V_{FB} ripple propagates a delay to the HS-FET driver, as shown in Figures 4 and 5. Jitter can affect system stability, with noise immunity proportional to the steepness of V_{FB} 's downward slope. However, V_{FB} ripple does not directly affect noise immunity.

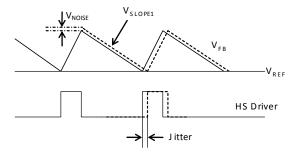


Figure 4—Jitter in PWM Mode

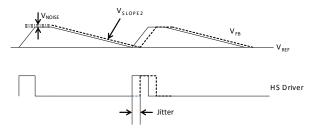


Figure 5—Jitter in Skip Mode

Selecting the Output Capacitors

The traditional constant-on-time control scheme is intrinsically unstable if output capacitor's ESR is not large enough as an effective current-sense resistor. Ceramic capacitors usually can not be used as output capacitor.

Figure 6 shows an equivalent circuit in PWM mode with the HS-FET off. To realize the stability, the ESR value should be chosen as follow:

$$R_{ESR} \ge \frac{\frac{T_{SW}}{0.7 \times \pi} + \frac{T_{ON}}{2}}{C_{OUT}}$$
 (2)

T_{SW} is the switching period.

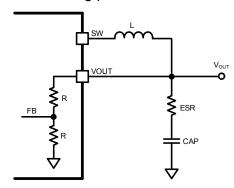


Figure 6—Simplified Circuit in PWM Mode

The NB670 has built in internal ramp compensation to make sure the system is stable even without the help of output capacitor's ESR; and thus the pure ceramic capacitor solution can be applicant. The pure ceramic capacitor solution can significantly reduce the output ripple, total BOM cost and the board area.

Configuring the EN Control

The NB670 has two enable pins to control the on/off of the internal regulators.

ENLDO is used to enable or disable the whole

chip. Once ENLDO is off, all the regulators include Vcc will be off. ENLDO is internally pulled high so it can be floated in the normal operation. When ENLDO is pulled high, Pull En high to turn on the Buck regulator also the charge pump clk, and pull EN low to turn them off. Do not float the EN pin.

See Table1 for the logics to control the regulators

Table 1—ENLDO/EN Control

| State | ENLDO | EN | VCC | VOUT/CLK | LDO |
|--------|-------|----|-----|----------|-----|
| S0 | 1 | 1 | ON | ON | ON |
| S3 | 1 | 0 | ON | OFF | ON |
| S4/S5 | 0 | 0 | OFF | OFF | OFF |
| Others | 0 | 1 | OFF | OFF | OFF |

For automatic start-up the EN pin can be pulled up to input voltage through a resistive voltage divider. Choose the values of the pull-up resistor (R_{UP} from Vin pin to EN pin) and the pull-down resistor (R_{DOWN} from EN pin to GND) to determine the automatic start-up voltage:

$$V_{\text{IN-START}} = 1.25 \times \frac{R_{\text{UP}} + R_{\text{DOWN}}}{R_{\text{DOWN}}} (V)$$
 (3)

For example, for $R_{\text{UP}}\text{=}150\text{k}\Omega$ and $R_{\text{DOWN}}\text{=}51\text{k}\Omega,$ the $V_{\text{IN-START}}$ is set at 4.92V.

To avoid noise, a 10nF ceramic capacitor from EN to GND is recommended.

There is an internal Zener diode on the EN pin, which clamps the EN pin voltage to prevent it from running away. The maximum pull up current assuming a worst case 12V internal Zener clamp should be less than 1mA.

Therefore, when EN is driven by an external logic signal, the EN voltage should be lower than 12V; when EN is connected with VIN through a pull-up resistor or a resistive voltage divider, the resistance selection should ensure the maximum pull up current less than 1mA.

If using a resistive voltage divider and VIN higher than 12V, the allowed minimum pull-up resistor R_{UP} should meet the following equation:

$$\frac{V_{IN}(V) - 12}{R_{IJP}(k\Omega)} - \frac{12}{R_{DOWN}(k\Omega)} < 1(mA)$$
 (4)

Especially, just using the pull-up resistor R_{UP} (the pull-down resistor is not connected), the $V_{\text{IN-START}}$ is determined by input UVLO, and the minimum resistor value is:

$$R_{UP}(k\Omega) > \frac{V_{IN}(V) - 12}{1(mA)}$$
 (5)

A typical pull-up resistor is $499k\Omega$.

Soft Start

The NB670 employs soft start (SS) mechanism to ensure smooth output during power-up. When the EN pin becomes high, the internal reference voltage ramps up gradually; hence, the output voltage ramps up smoothly, as well. Once the reference voltage reaches the target value, the soft start finishes and it enters into steady state operation.

If the output is pre-biased to a certain voltage during startup, the IC will disable the switching of both high-side and low-side switches until the voltage on the internal reference exceeds the sensed output voltage at the internal FB node.

3.3V Linear Regulator

There is a built-in 100-mA standby linear regulator which outputs 3.3V.The 3.3V LDO is intended mainly for auxiliary 3.3V supply for the notebook system during standby mode.

Add a ceramic capacitor with a value between 4.7µF and 22uF placed close to the LDO pins to stabilize LDOs.

3.3V LDO Switch Over

When the output voltage becomes higher than 3.15V and the power good flag is generated, internal 3.3V LDO regulator is shut off and the LDO output is connected to Vout pin by the internal switch over MOSFET. The 20us power good deglitch time helps a switch over without glitch.

CLK for Charge Pump

The 300kHZ CLK signal can be used to drive an external charge pump circuit to generate approximately 12-15V DC voltage. The CLK voltage becomes available once the VIN is higher than UVLO threshold. Example of charge pump control circuit is shown in Figure 7.

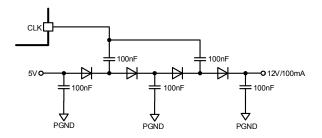


Figure 7—Charge Pump Circuit

Power Good (PG)

The NB670 has power-good (PG) output used to indicate whether the output voltage of the Buck regulator is ready or not. The PG pin is the open drain of a MOSFET. It should be connected to $V_{\rm CC}$ or other voltage source through a resistor (e.g. 100k). After the input voltage is applied, the MOSFET is turned on so that the PG pin is pulled to GND before SS is ready. After FB voltage reaches 95% of REF voltage, the PG pin is pulled high after a delay. The PG delay time is 0.5ms.

When the FB voltage drops to 85% of REF voltage, the PG pin will be pulled low.

Over Current Protection

NB670 has cycle-by-cycle over current limiting control. The current-limit circuit employs a "valley" current-sensing algorithm. The part uses the Rds(on) of the low side MOSFET as a current-sensing element. If the magnitude of the current-sense signal is above the current-limit threshold, the PWM is not allowed to initiate a new cycle.

The trip level is fixed internally. The inductor current is monitored by the voltage between GND pin and SW pin. GND is used as the positive current sensing node so that GND should be connected to the source terminal of the bottom MOSFET.

Since the comparison is done during the high side MOSFET OFF and low side MOSFET ON state, the OC trip level sets the valley level of the inductor current. Thus, the load current at over-current threshold, $I_{\rm OC}$, can be calculated as follows:

$$I_{OC} = I_{limit} + \frac{\Delta I_{inductor}}{2}$$
 (6)

In an over-current condition, the current to the load exceeds the current to the output capacitor; thus the output voltage tends to fall off. Eventually, it will end up with crossing the under voltage protection threshold and shutdown. And fault latching can be reset by EN going low or Power-cycling of VIN.

Over/Under-Voltage Protection (OVP/UVP)

NB670 monitors output voltage to detect over and under voltage. When the feedback voltage becomes higher than 115% of the target voltage, the controller will enter Dynamic Regulation Period. During this period, the LS will off when the LS current goes to -1A, this will then discharge the output and try to keep it within the normal range. If the dynamic regulation can not limit the increasing of the Vo, once the feedback voltage becomes higher than 130% of the feedback voltage, the OVP comparator output goes high and the circuit latches as the high-side MOSFET driver OFF and the low-side MOSFET driver turn on acting as an -1A current source.

When the feedback voltage becomes lower than 60% of the target voltage, the UVP comparator output goes high if the UV still occurs after 26us delay; then the fault latch will be triggered---latches HS off and LS on; the LS FET keeps on until the inductor current goes zero. Also fault latching can be reset by EN going low or Power-cycling of VIN.

UVLO Protection

The NB670 has under-voltage lock-out protection (UVLO). When the VCC voltage is higher than the UVLO rising threshold voltage, the part will be powered up. It shuts off when the VIN voltage is lower than the UVLO falling threshold voltage. This is non-latch protection. The part is disabled when the VCC voltage falls below 4.65V. Besides fault latching can be reset by EN going low or Power-cycling of VIN. If an application requires a higher under-voltage lockout (UVLO), use the EN pin as shown in Figure 8 to adjust the input voltage UVLO by using two external resistors. It is recommended to use the enable resistors to set the UVLO falling threshold (VSTOP) above 4.65V. The rising threshold (VSTART) should be set to provide enough hysteresis to allow for any input supply variations.

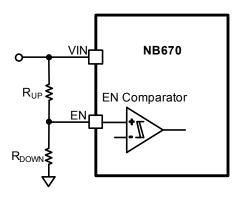


Figure 8—Adjustable UVLO

Thermal Shutdown

Thermal shutdown is employed in the NB670. The junction temperature of the IC is internally monitored. If the junction temperature exceeds the threshold value (typical 150°C), the converter shuts off. This is a non-latch protection. There is about 25°C hysteresis. Once the junction temperature drops to about 125°C, it initiates a SS.

Output Discharge

NB670 discharges the output when EN is low, or the controller is turned off by the protection functions (UVP & OCP, OCP, OVP, UVLO, and thermal shutdown). The part discharges outputs using an internal 6Ω MOSFET.

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APPLICATION INFORMATION

Input Capacitor

The input current to the step-down converter is discontinuous and therefore requires a capacitor to supply the AC current to the step-down converter while maintaining the DC input voltage. Ceramic capacitors are recommended for best performance and should be placed as close to the VIN pin as possible. Capacitors with X5R and X7R ceramic dielectrics are recommended because they are fairly stable with temperature fluctuations.

The capacitors must also have a ripple current rating greater than the maximum input ripple current of the converter. The input ripple current can be estimated as follows:

$$I_{CIN} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times (1 - \frac{V_{OUT}}{V_{IN}})}$$
 (7)

The worst-case condition occurs at $V_{IN} = 2V_{OUT}$, where:

$$I_{CIN} = \frac{I_{OUT}}{2} \tag{8}$$

For simplification, choose the input capacitor with an RMS current rating greater than half of the maximum load current.

The input capacitance value determines the input voltage ripple of the converter. If there is an input voltage ripple requirement in the system, choose the input capacitor that meets the specification.

The input voltage ripple can be estimated as follows:

$$\Delta V_{IN} = \frac{I_{OUT}}{F_{SW} \times C_{IN}} \times \frac{V_{OUT}}{V_{IN}} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
 (9)

Under worst-case conditions where $V_{IN} = 2V_{OUT}$:

$$\Delta V_{IN} = \frac{1}{4} \times \frac{I_{OUT}}{F_{SW} \times C_{IN}}$$
 (10)

Output Capacitor

The output capacitor is required to maintain the DC output voltage. Ceramic or POSCAP capacitors are recommended. The output voltage ripple can be estimated as:

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{F_{\text{SW}} \times L} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}) \times (R_{\text{ESR}} + \frac{1}{8 \times F_{\text{SW}} \times C_{\text{OUT}}}) \quad (11)$$

In the case of ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance. The output voltage ripple is mainly caused by the capacitance. For simplification, the output voltage ripple can be estimated as:

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{8 \times F_{\text{SW}}^2 \times L \times C_{\text{OUT}}} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}})$$
 (12)

In the case of POSCAP capacitors, the ESR dominates the impedance at the switching frequency. The ramp voltage generated from the ESR is high enough to stabilize the system. Therefore, an external ramp is not needed. A minimum ESR value around $12m\Omega$ is required to ensure stable operation of the converter. For simplification, the output ripple can be approximated as:

$$\Delta V_{OUT} = \frac{V_{OUT}}{F_{SW} \times L} \times (1 - \frac{V_{OUT}}{V_{IN}}) \times R_{ESR}$$
 (13)

Maximum output capacitor limitation should be also considered in design application. NB670 has an around 1.8ms soft-start time period. If the output capacitor value is too high, the output voltage can't reach the design value during the soft-start time, and then it will fail to regulate. The maximum output capacitor value C_{O_MAX} can be limited approximately by:

$$C_{\text{O} \text{MAX}} = (I_{\text{LIM} \text{AVG}} - I_{\text{OUT}}) \times T_{\text{ss}} / V_{\text{OUT}}$$
 (14)

Where, I_{LIM_AVG} is the average start-up current during soft-start period. T_{ss} is the soft-start time.

Inductor

The inductor is necessary to supply constant current to the output load while being driven by the switched input voltage. A larger-value inductor will result in less ripple current that will result in lower output ripple voltage. However, a larger-value inductor will have a larger physical footprint, higher series resistance, and/or lower saturation current. A good rule for determining the inductance value is to design the peak-to-peak ripple current in the inductor to be in the range of 30% to 40% of the maximum output

current, and that the peak inductor current is below the maximum switch current limit. The inductance value can be calculated by:

$$L = \frac{V_{\text{OUT}}}{F_{\text{SW}} \times \Delta I_{\text{L}}} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}})$$
 (15)

Where ΔI_L is the peak-to-peak inductor ripple current.

The inductor should not saturate under the maximum inductor peak current, where the peak inductor current can be calculated by:

$$I_{LP} = I_{OUT} + \frac{V_{OUT}}{2F_{SW} \times L} \times (1 - \frac{V_{OUT}}{V_{IN}})$$
 (16)

PCB Layout Guide

The following guidelines should be followed when designing the PC board for the NB670:

 The high current paths (GND, IN, and SW) should be placed very close to the device with short, direct and wide traces.

- 2. Put the input capacitors as close to the IN and GND pins as possible.
- Put the decoupling capacitor as close to the VCC and AGND pins as possible. Place the Cap close to AGND if the distance is long. And place >3 Vias if via is required to reduce the leakage inductance.
- Keep the VOUT sensing trace far away from the SW node. Vias should also be avoided on the VOUT sensing trace.
- 5. Keep the BST voltage path (BST, C3, and SW) as short as possible.
- 6. Keep the IN and GND pads connected with large copper and use at least two layers for IN and GND trace to achieve better thermal performance. Also, add several Vias with 10mil_drill/18mil_copper_width close to the IN and GND pads to help on thermal dissipation.
- 7. AGND connects PGND with KELVIN Connecting.
- 8. Four-layer layout is strongly recommended to achieve better thermal performance.

Note:

Please refer to the PCB Layout Application Note for more details.

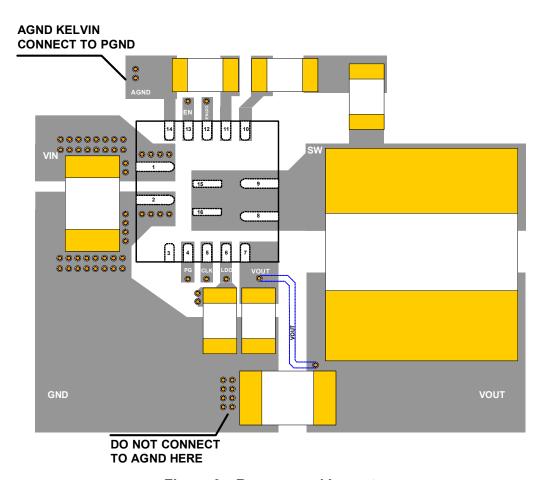


Figure 9—Recommend Layout

Recommend Design Example

A typical application schematic is shown in Figure 10 when large ESR caps are used, and Figure 11 shows the schematic when low ESR caps are applied. The typical performance and

circuit waveforms have been shown in the Typical Performance Characteristics section. For more possible applications of this device, please refer to related Evaluation Board Datasheets.

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TYPICAL APPLICATION

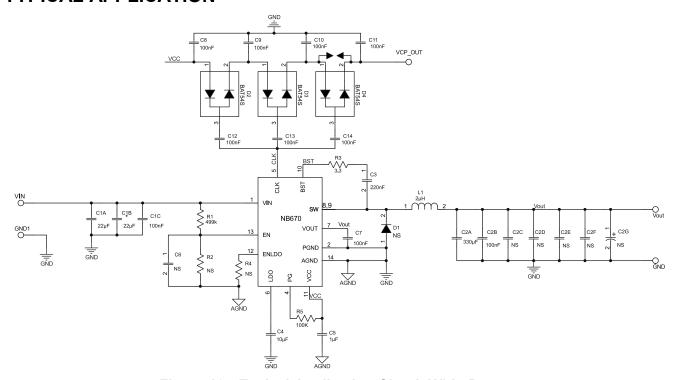


Figure 10---Typical Application Circuit With Poscap NB670 Vin=4.8-22V, Vout=3.3V, lout=6A, Fsw=500kHz

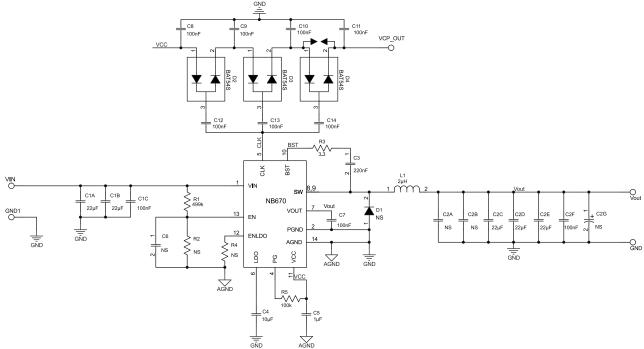
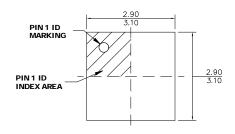
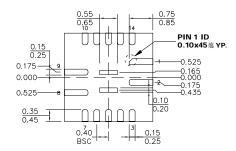


Figure 11---Typical Application Circuit With Low ESR Ceramic Capacitor NB670 Vin=4.8-22V, Vout=3.3V, lout=6A, Fsw=500kHz

PACKAGE INFORMATION

QFN-16 (3mmX3mm)



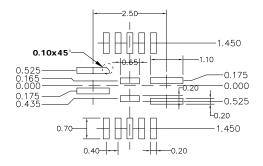


TOP VIEW

BOTTOM VIEW



SIDE VIEW



RECOMMENDED LAND PATTERN

NOTE:

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
 2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
- 3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS MAX.
- 4) JEDEC REFERENCE IS MO-220.
- 5) DRAWING IS NOT TO SCALE.

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XCL207A123CR-G MPM54304GMN-0002 MPM54304GMN-0003 XDPE132G5CG000XUMA1 DA9121-B0V76 MP8757GL-P

MIC23356YFT-TR LD8116CGL HG2269M/TR OB2269 XD3526 U6215A U6215B U6620S LTC3803ES6#TR LTC3803ES6#TRM

LTC3412IFE LT1425IS MAX25203BATJA/VY+ MAX77874CEWM+ XC9236D08CER-G ISL95338IRTZ MP3416GJ-P BD9S201NUX-CE2 MP5461GC-Z MPQ4415AGQB-Z MPQ4590GS-Z MCP1603-330IMC MCP1642B-18IMC